TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

TA8409S,TA8409F

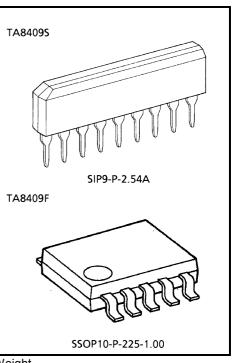
BRIDGE DRIVER

TA8409S and TA8409F are bridge driver with output voltage control.

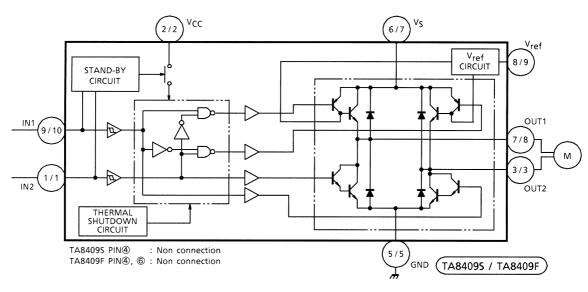
FEATURES

- Modes available (CW / CCW / STOP / BRAKE)
- Output current up to 0.4 A (AVE) and 1.0 A (PEAK)
- Wide range of operating voltage VCC (opr.) = 4.5~20 V VS (opr.) = 0~20 V
 - $V_{ref (opr.)} = 0 \sim 20 V \quad (V_{ref} \le V_S)$
- Built-in thermal shutdown
- Standby mode available (STOP MODE)
- Hysteresis for all inputs.

BLOCK DIAGRAM



Weight SIP9-P-2.54A : 0.92 g (Typ.) SSOP10-P-225-1.00 : 0.09 g (Typ.)



980910EBA2

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PIN FUNCTION

TA8409S

PIN No.	SYMBOL	FUNCTIONAL DESCRIPTION			
1	IN2	Input terminal			
2	V _{CC}	Supply voltage terminal for logic			
3	OUT2	Output terminal			
4	NC	Non connection			
5	GND	GND terminal			
6	VS	Supply voltage terminal for motor driver			
7	OUT1	Output terminal			
8	V _{ref}	Reference voltage terminal for control circuit			
9	IN1	Input terminal			

TA8409F

PIN No.	SYMBOL	FUNCTIONAL DESCRIPTION		
1	IN2	Input terminal		
2	V _{CC}	Supply voltage terminal for logic		
3	OUT2	Output terminal		
4	NC	Non connection		
5	GND	GND terminal		
6	NC	Non connection		
7	VS	Supply voltage terminal for motor driver		
8	OUT1	Output terminal		
9	V _{ref}	Reference voltage terminal for control circuit.		
10	IN1	Input terminal		

FUNCTION

INPUT		OUT	MODE	
IN 1	IN 2	OUT1	OUT2	MB
0	0	80	8	STOP
1	0	Н	L	CW / CCW
0	1	L	Н	CCW / CW
1	1	L	L	BRAKE

∞: High impedance

Note: Inputs are all high active type.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT	
Supply Voltage		V _{CC}	V _{CC} 25		
Motor Drive Voltage		VS	25	V	
Reference Voltage		V _{ref}	25	V	
Output Current	PEAK	I _{O (PEAK)}	1.0	A	
Output Current	AVE	I _{O (AVE.)}	0.4		
Power Dissipation	TA8409F	Po	0.735 (Note)	w	
	TA8409S	PD	0.95		
Operating Temperature		T _{opr}	-30~75	°C	
Storage Temperature		T _{stg}	-55~150	°C	

Note: This rating is obtained by mounting on $50 \times 50 \times 1.6$ mm PCB that occupied above 30% of copper area.

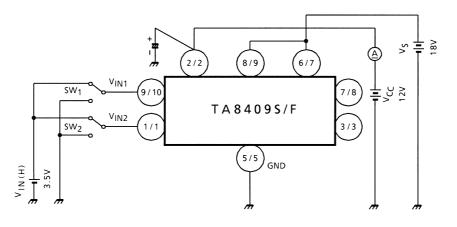
ELECTRICAL CHARACTERISTICS (Ta = 25°C, V_{CC} = 12 V, V_S = 18 V)

CHARACTERISTIC		SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN	TYP.	MAX	UNIT	
Supply Current		I _{CC1}	1	Output OFF, CW / CCW mode - 10.0		15.0	mA		
		I _{CC2}	1	Output OFF, STOP mode - 0		50	μA		
		I _{CC3}	1	output OFF, BREAK mode – 6.5		10.0	mA		
Input Operating	1 (High)	V _{IN 1}	2	T _j = 25°C IN1, 2	3.5	—	5.5	v	
Voltage	2 (Low)	V _{IN 2}	2	T _j = 25°C IN1, 2	GND	—	0.8		
Input Current		I _{IN}	2	Sink mode, V _{IN} = 3.5 V	_	3	10	μA	
Input Hysteresis Volta	age	ΔV_T	2	—	_	0.7	—	V	
Saturation Voltage	Upper Side	V _{SAT U-1}	3	$V_{ref} = V_S, V_{OUT} - V_S$ measure I _O = 0.2 A, CW / CCW mode	_	0.9	1.2	V	
	Lower Side	V _{SAT L-1}	3	$V_{ref} = V_S$, V_{OUT} -GND measure I _O = 0.2 A, CW / CCW mode	_	0.8	1.2		
	Upper Side	V _{SAT U-2}	3	$V_{ref} = V_S, V_{OUT} - V_S$ measure $I_O = 0.4 A, CW / CCW$ mode	_	1.0	1.35		
	Lower Side	V _{SAT L-2}	3	$V_{ref} = V_S, V_{OUT}$ -GND measure $I_O = 0.4 A, CW / CCW$ mode	_	0.9	1.35		
Output Voltage		VSAT U-1'	3	V_{ref} = 10 V, V_{OUT} -GND measure I_O = 0.2 A	10.4	11.2	12.2	v	
		VSAT U-2'	3	V_{ref} = 10 V, V_{OUT} -GND measure I_O = 0.4 A	_	10.9	_		
Output Transistor Leakage Current	Upper Side	ILU	4	V _L = 25 V	_	_	50	μA	
	Lower Side	ILL	4	V _L = 25 V	_	—	50		
Diode Forward Voltage	Upper Side	V _{FU-1}	5	I _F = 0.4 A	_	1.5	_	V	
	Lower Side	V _{FL-1}	5	I _F = 0.4 A	_	0.9	_		
Reference Current		I _{ref}	2	V _{ref} = 10 V, source mode	_	20	40	μA	

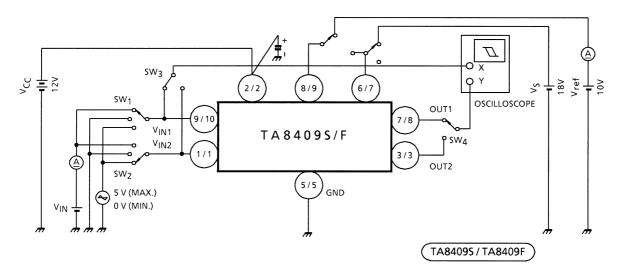
<u>TOSHIBA</u>

TEST CIRCUIT 1

ICC1, ICC2, ICC3

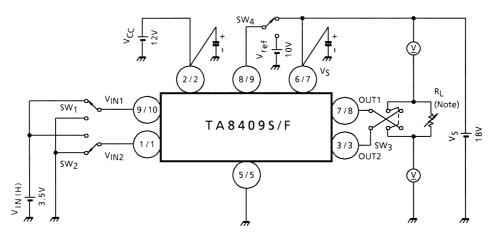


TEST CIRCUIT 2 $V_{IN1}, V_{IN2}, I_{IN}, \Delta V_T, I_{ref}$



TEST CIRCUIT 3

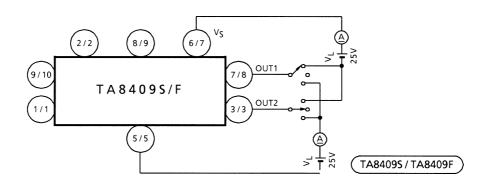
VSAT U-1, 2, VSAT L-1, 2, VSAT U-1', 2'



Note: Calibrate I_{OUT} to 0.2 / 0.4 A by RL.

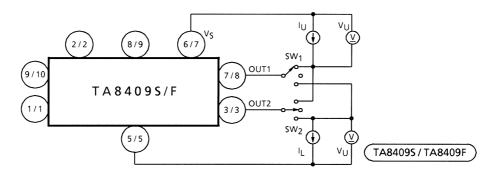
TEST CIRCUIT 4

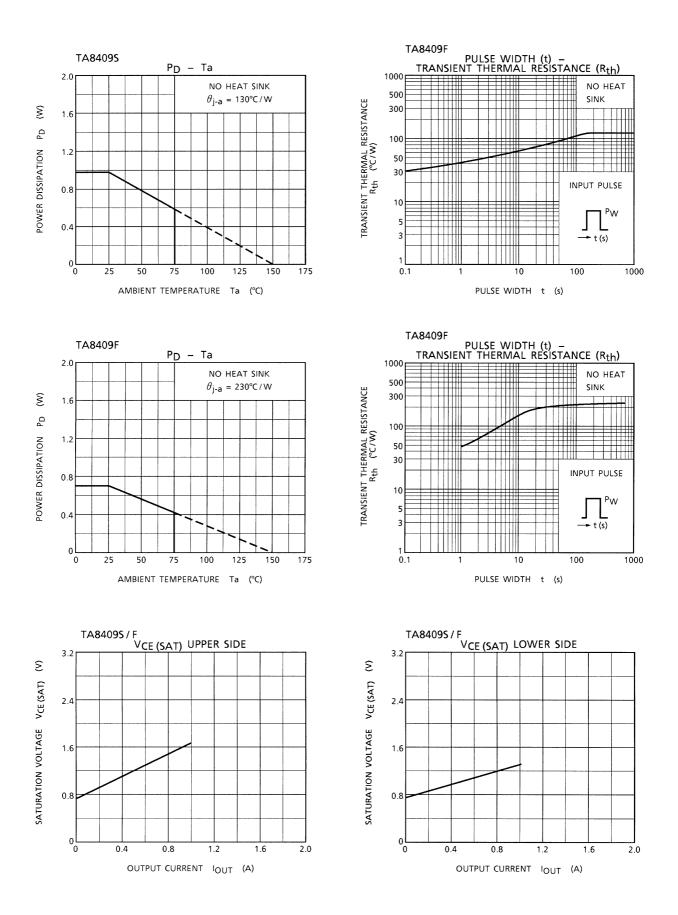
I_{L U, L}



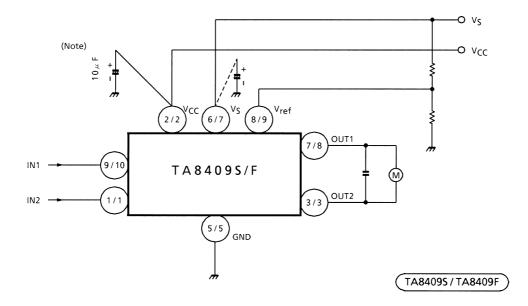
TEST CIRCUIT 5

 $V_{F \; U-1, \; 2}, \, V_{F \; L-1, \; 2}$





APPLICATION CIRCUIT

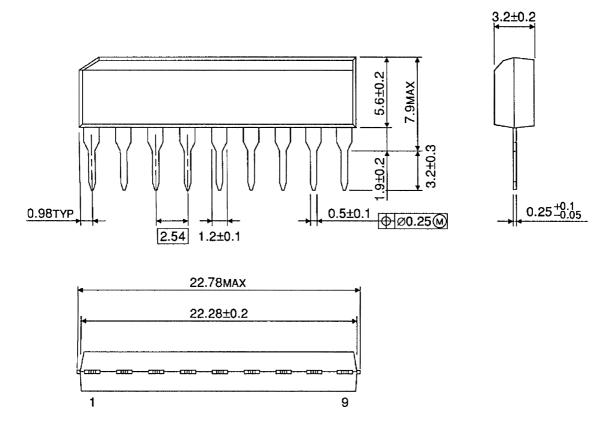


- Note 1: Connect if required.
- Note 2: Utmost care is necessary in the design of the output line, V_S and GND line since IC may be destroyed due to short–circuit between outputs, air contamination fault, or fault by improper grounding.
- Note 3: Be careful when switching the input because rush current may occur.
- When switching, stop mode should be entered or current limitation resister R should be inserted. Note 4: The IC functions cannot be guaranteed when turning power on of off.
- Before using the IC for application, check that there are no problems.

OUTLINE DRAWING

SIP9-P-2.54A

Unit: mm



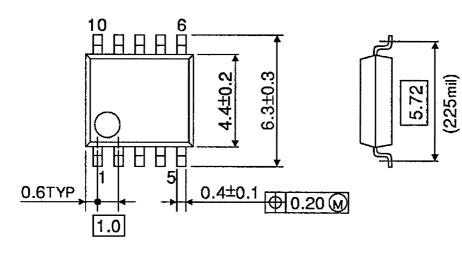
Weight: 0.92 g (Typ.)

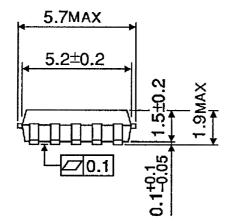
TA8409S/F

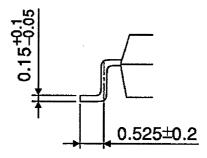
OUTLINE DRAWING

SSOP10-P-225-1.00

Unit: mm







Weight: 0.09 g (Typ.)